

#### FEATURES

- Epitaxial planar die construction
- Complementary NPN Type available(MMBT2222A)
- Marking: 2F

#### MAXIMUM RATINGS (T₂=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
lc	Collector Current -Continuous	-600	mA
Pc	Collector Dissipation	300	mW
Reja	Thermal Resistance, Junction to Ambient	417	°C/W
T <sub>J</sub> ,Tstg	Operation Junction and Storage Temperature Range	-55~+150	°C



#### ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

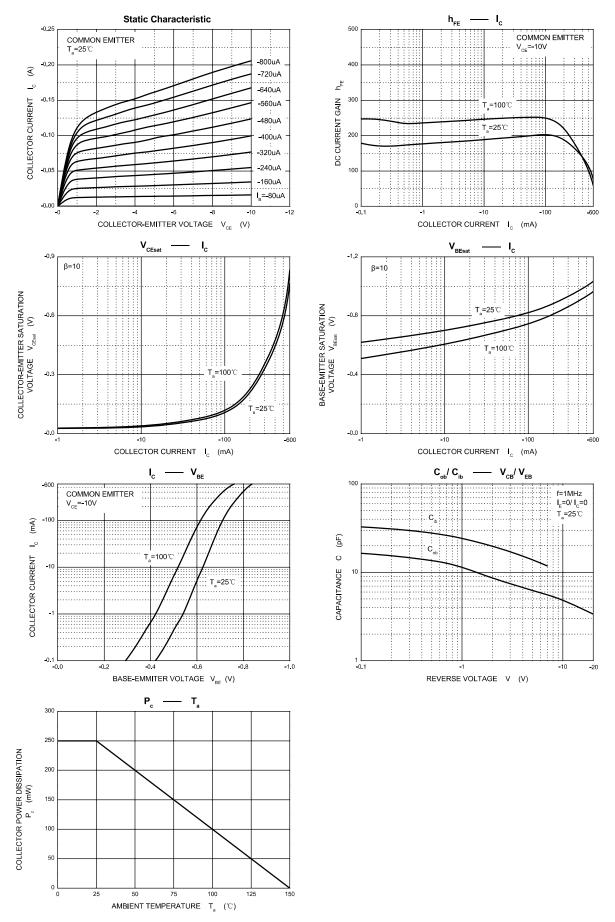
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =-10μA,I <sub>E</sub> =0	-60	- 76	max	V
Collector-emitter breakdown voltage	V(BR)CEO*	$I_{\rm C}$ =-10mA,I <sub>B</sub> =0	-60			v
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>					V
Collector cut-off current	Сво	V <sub>CB</sub> =-50V,I <sub>E</sub> =0	-		-20	nA
Base cut-off current	I <sub>EBO</sub>	$V_{EB}$ =-3V, I <sub>C</sub> =0			-10	nA
Collector cut-off current	I <sub>CEX</sub>	V <sub>CE</sub> =-30 V, V <sub>BE(off)</sub> =-0.5V			-50	nA
	h <sub>FE(1)</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-150mA	100		300	
	h <sub>FE(2)</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-0.1mA	75			 I
DC current gain	h <sub>FE(3)</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-1mA	100			 I
	h <sub>FE(4)</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-10mA	100			
	h <sub>FE(5)</sub>	V <sub>CE</sub> =-10V,I <sub>C</sub> =-500mA	50			
	V <sub>CE(sat)*</sub>	I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA			-0.4	V
Collector-emitter saturation voltage	V <sub>CE(sat)*</sub>	I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA			-1.6	V
Base-emitter saturation voltage	V <sub>BE(sat)*</sub>	I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA			-1.3	V
Dase-emitter saturation voltage	V <sub>BE(sat)*</sub>	I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA			-2.6	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =-20V,I <sub>C</sub> =-50mA,f=100MHz	200			MHz
Delay time	t <sub>d</sub>				10	ns
Rise time	tr	V <sub>CE</sub> =-30V,I <sub>C</sub> =-150mA, <sub>B1</sub> =-15mA			25	ns
Storage time	ts	V <sub>CE</sub> =-6V,I <sub>C</sub> =-150mA,			225	ns
Fall time	t <sub>f</sub>	I <sub>B1</sub> =- I <sub>B2</sub> =- 15mA			60	ns

\*Pulse test: t<sub>p</sub>≤300μs, δ≤0.02.





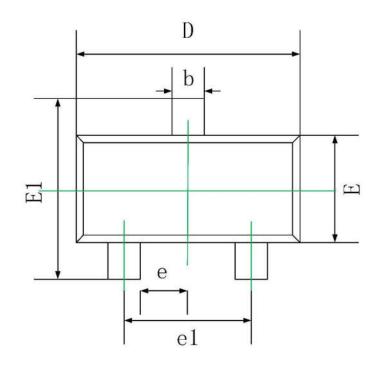
### **Typical Characteristics**

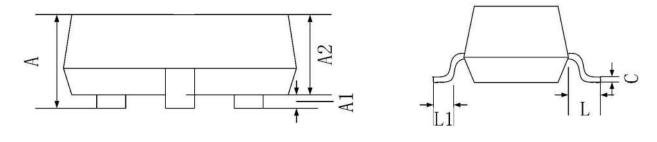






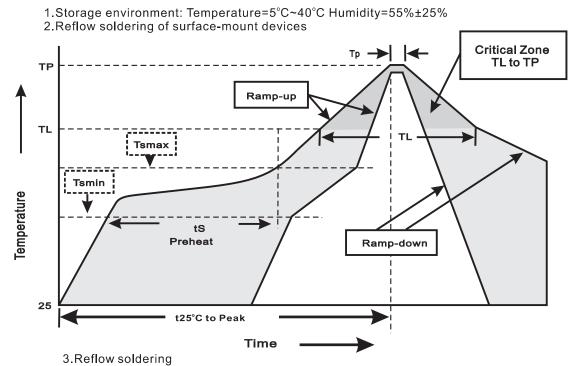
## **SOT-23 Package Information**





Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
e	0.950 TYP. 0.037 TYP.		TYP.		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF.		0.022 REF.		
L1	0.300	0.500	0.012	0.020	





### Suggested thermal profiles for soldering processes

Profile Feature	Soldering Condition
Average ramp-up rate(T∟ to T⊵)	<3°C/sec
Preheat Temperature Min(Tsmin)	150°C
Temperature Max(Tsmax)	200°C
Time(min to max)(ts)	60~120sec
Tsmax to T∟	
-Ramp-upRate	<3°C/sec
Time maintained above:	
Temperature(T∟)	217°C
-Time(t∟)	60~260sec
Peak Temperature(T⊧)	255°C-0/+5°C
Time within 5°C of actual Peak	10~30sec
Temperature(t <sub>P</sub> )	10 00300
Ramp-down Rate	<6°C/sec
Fime 25°C to Peak Temperature	<6minutes

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